SBS 1.1-COMPLIANT GAS GAUGE ENABLED WITH IMPEDANCE TRACK™ TECHNOLOGY FOR USE WITH THE bq29330

Check for Samples: bq20z60-R1

FEATURES

- **Next Generation Patented Impedance Track™ Technology Accurately Measures Available Charge in Li-Ion and Li-Polymer Batteries**
  - **Better Than 1% Error Over the Lifetime of the Battery**
- **Supports the Smart Battery Specification SBS V1.1**
- **Flexible Configuration for 2-, 3-, and 4-Series Li-Ion and Li-Polymer Cells**
- **Powerful 8-Bit RISC CPU With Ultralow Power Modes**
- **Full Array of Programmable Protection Features**
  - **Voltage, Current, and Temperature**
- **Satisfies JEITA Guidelines**
- **Added Flexibility to Handle More Complex Charging Profiles**
- **Lifetime Data Logging**
- **Drives 3-, 4-, or 5-Segment LED Display for Battery-Pack Conditions**
- **Supports SHA-1 Authentication**
- **Available in 30-Pin TSSOP (DBT) and 32-Pin QFN (RSM) Packages**

APPLICATIONS

- **Notebook PCs**
- **Medical and Test Equipment**
- **Portable Instrumentation**

DESCRIPTION

The bq20z60-R1 SBS-compliant gas gauge and protection IC, incorporating patented Impedance Track™ technology, is designed for battery-pack or in-system installation. The bq20z60-R1 measures and maintains an accurate record of available charge in Li-Ion or Li-Polymer batteries, using its integrated high-performance analog peripherals. The bq20z60-R1 monitors capacity change, battery impedance, open-circuit voltage, and other critical parameters of the battery pack, which reports the information to the system host controller over a serial-communication bus. It is designed to work with the bq29330 analog front-end (AFE) protection IC to maximize functionality and safety, while minimizing external component count and cost in smart battery circuits.

The Impedance Track™ technology continuously analyzes the battery impedance, resulting in superior gas-gauging accuracy. This enables the remaining capacity to be calculated with discharge rate, temperature, and cell aging, which are all accounted for during each stage of every cycle with high accuracy.

Table 1. AVAILABLE OPTIONS

T_A	PACKAGE			
	30-PIN TSSOP (DBT) Tube	**30-PIN TSSOP (DBT) Tape & Reel**	**32-PIN QFN (RSM) Tube**	**32-PIN QFN (RSM) Tape & Reel**
–40°C to 85°C	bq20z60-R1DBT[1]	bq20z60-R1DBTR[2]	bq20z60-R1RSM[1]	bq20z60-R1RSMR[2]

(1) A single tube quantity is 60 units.
(2) A single reel quantity is 2000 units.

⚠️ Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Impedance Track is a trademark of Texas Instruments.

THERMAL INFORMATION

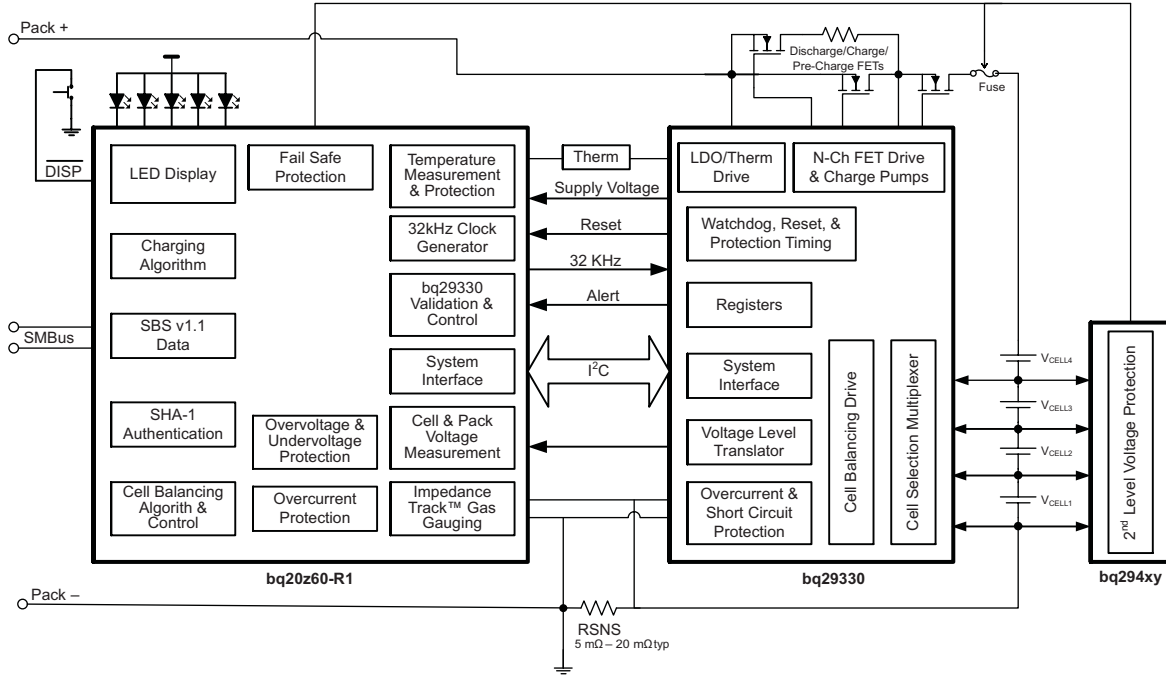| THERMAL METRIC[1]		bq20z60-R1		UNITS
		TSSOP (DBT)	QFN (RSM)	
		30 PINS	32 PINS	
$\theta_{JA, High K}$	Junction-to-ambient thermal resistance [2]	81.4	37.4	°C/W
$\theta_{JC(top)}$	Junction-to-case(top) thermal resistance [3]	16.2	30.6	
θ_{JB}	Junction-to-board thermal resistance [4]	34.1	7.7	
ψ_{JT}	Junction-to-top characterization parameter [5]	0.4	0.4	
ψ_{JB}	Junction-to-board characterization parameter [6]	33.6	7.5	
$\theta_{JC(bottom)}$	Junction-to-case(bottom) thermal resistance [7]	N/A	2.6	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.
(2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
(5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
(6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SYSTEM PARTITIONING DIAGRAM
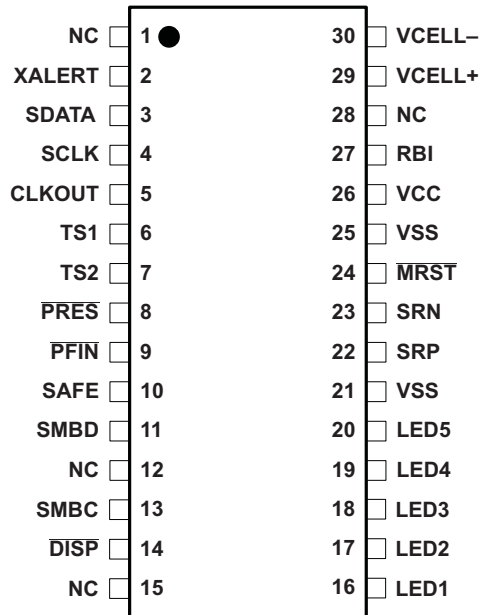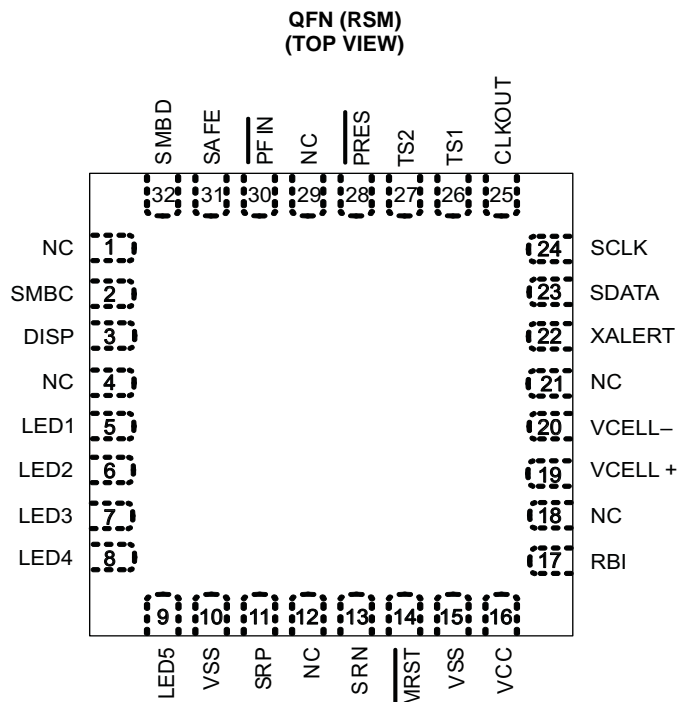
TSSOP (DBT) PIN FUNCTIONS

TSSOP (DBT)
(TOP VIEW)

NC	1 ●	30	VCELL–
XALERT	2	29	VCELL+
SDATA	3	28	NC
SCLK	4	27	RBI
CLKOUT	5	26	VCC
TS1	6	25	VSS
TS2	7	24	$\overline{\text{MRST}}$
$\overline{\text{PRES}}$	8	23	SRN
$\overline{\text{PFIN}}$	9	22	SRP
SAFE	10	21	VSS
SMBD	11	20	LED5
NC	12	19	LED4
SMBC	13	18	LED3
$\overline{\text{DISP}}$	14	17	LED2
NC	15	16	LED1

Table 2. TSSOP (DBT) PIN CONFIGURATIONS

PIN		I/O[1]	DESCRIPTION
NO.	NAME		
1	NC	—	Not used—leave floating
2	XALERT	I	Input from bq29330 XALERT output
3	SDATA	I/O	Data transfer to and from bq29330
4	SCLK	I/O	Communication clock to the bq29330
5	CLKOUT	O	32.768-kHz output for the bq29330. This pin should be directly connected to the AFE.
6	TS1	I	1st Thermistor voltage input connection to monitor temperature
7	TS2	I	2nd Thermistor voltage input connection to monitor temperature
8	$\overline{PRES}$	I	Active low input to sense system insertion. This typically requires additional ESD protection.
9	$\overline{PFIN}$	I	Active low input to detect secondary protector output status, and to allow the bq20z60-R1 to report the status of the 2nd level protection output
10	SAFE	OD	Active high output to enforce additional level of safety protection; for example, fuse blow
11	SMBD	I/OD	SMBus data open-drain bidirectional pin used to transfer address and data to and from the bq20z60-R1
12	NC	—	Not used—leave floating
13	SMBC	I/OD	SMBus clock open-drain bidirectional pin used to clock the data transfer to and from the bq20z60-R1
14	$\overline{DISP}$	I	Display control for the LEDs. This pin is typically connected to bq29330 REG via a 100-KΩ resistor and a push-button switch connect to VSS.
15	NC	—	Not used—leave floating
16	LED1	O	LED1 display segment that drives an external LED depending on the firmware configuration
17	LED2	O	LED2 display segment that drives an external LED depending on the firmware configuration
18	LED3	O	LED3 display segment that drives an external LED depending on the firmware configuration
19	LED4	O	LED4 display segment that drives an external LED depending on the firmware configuration
20	LED5	O	LED5 display segment that drives an external LED depending on the firmware configuration
21	VSS	—	Negative supply voltage
22	SRP	IA	Connections for a small-value sense resistor to monitor the battery charge- and discharge-current flow
23	SRN	IA	Connections for a small-value sense resistor to monitor the battery charge- and discharge-current flow
24	$\overline{MRST}$	I	Master reset input that forces the device into reset when held low. This pin must be held high for normal operation.
25	VSS	P	Negative supply voltage
26	VCC	P	Positive supply voltage
27	RBI	P	RAM backup input. Connect a capacitor to this pin and VSS to protect loss of RAM data in case of short circuit condition.
28	NC	—	Not used—leave floating
29	VCELL+	I	Input from bq29330 used to read a scaled value of individual cell voltages
30	VCELL–	I	Input from bq29330 used to read a scaled value of individual cell voltages

(1) I = Input, IA = Analog input, I/O = Input/output, I/OD = Input/Open-drain output, O = Output, OA = Analog output, P = Power

QFN (RSM) PIN FUNCTIONS

QFN (RSM)
(TOP VIEW)

QFN (RSM) PIN CONFIGURATIONS

NO.	PIN NAME	I/O[1]	DESCRIPTION
1	NC	—	Not used—leave floating
2	SMBC	I/OD	SMBus clock open-drain bidirectional pin used to clock the data transfer to and from the bq20z60-R1
3	DISP	—	Not used—leave floating
4	NC	—	Not used—leave floating
5	LED1	O	LED1 display segment that drives an external LED depending on the firmware configuration
6	LED2	O	LED2 display segment that drives an external LED depending on the firmware configuration
7	LED3	O	LED3 display segment that drives an external LED depending on the firmware configuration
8	LED4	O	LED4 display segment that drives an external LED depending on the firmware configuration
9	LED5	O	LED5 display segment that drives an external LED depending on the firmware configuration
10	VSS	P	Negative Supply Voltage
11	SRP	IA	Connections for a small-value sense resistor to monitor the battery charge- and discharge-current flow
12	NC	—	Not used—leave floating
13	SRN	IA	Connections for a small-value sense resistor to monitor the battery charge- and discharge-current flow
14	$\overline{MRST}$	I	Master reset input that forces the device into reset when held low. This pin must be held high for normal operation.
15	VSS	P	Negative Supply Voltage
16	VCC	P	Positive Supply Voltage
17	RBI	P	RAM backup input. Connect a capacitor to this pin and VSS to protect loss of RAM data in case of short circuit condition.
18	NC	—	Not used—leave floating
19	VCELL+	I	Input from bq29330 used to read a scaled value of individual cell voltages
20	VCELL–	I	Input from bq29330 used to read a scaled value of individual cell voltages

(1)   I = Input, IA = Analog input, I/O = Input/output, I/OD = Input/Open-drain output, O = Output, OA = Analog output, P = Power

QFN (RSM) PIN CONFIGURATIONS (continued)

PIN NO.	PIN NAME	I/O[1]	DESCRIPTION
21	NC	—	Not used—leave floating
22	XALERT	I	Input from bq29330 XALERT output
23	SDATA	I/O	Data transfer to and from bq29330
24	SCLK	I/O	Communication clock to the bq29330
25	CLKOUT	O	32.768-kHz output to the bq29330. This pin should be directly connected to the bq29330 AFE.
26	TS1	I	Thermistor 1 input
27	TS2	I	Thermistor 2 input
28	$\overline{PRES}$	I	Active low input to sense system insertion. This typically requires additional ESD protection.
29	NC	—	Not used—leave floating
30	$\overline{PFIN}$	I	Active low input to detect secondary protector output status, and to allow the bq20z60-R1 to report the status of the 2nd level protection output
31	SAFE	O	Active high output to enforce additional level of safety protection; for example, fuse blow
32	SMBD	I/OD	SMBus data open-drain bidirectional pin used to transfer address and data to and from the bq20z60-R1

ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature range (unless otherwise noted)[1]

		RANGE
V_{CC} relative to V_{SS}	Supply voltage range	–0.3 V to 2.75 V
$V_{(IOD)}$ relative to V_{SS}	Open-drain I/O pins	–0.3 V to 6 V
V_I relative to V_{SS}	Input voltage range to all other pins	–0.3 V to V_{CC} + 0.3 V
T_A	Operating free-air temperature range	–40°C to 85°C
T_{stg}	Storage temperature range	–65°C to 150°C

(1)   Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{CC}	Supply voltage		2.4	2.5	2.6	V
I_{CC}	Operating mode current	No flash programming		400[1]		µA
		bq20z60-R1 + bq29330		475		
$I_{(SLEEP)}$	Low-power storage mode current	Sleep mode		8[1]		µA
		bq20z60-R1 + bq29330		51		
$I_{(SHUTDOWN)}$	Low-power shutdown mode current	Shutdown mode		0.1	1	µA
		bq20z60-R1 + bq29330		0.2		
V_{OL}	Output voltage low SMBC, SMBD, SDATA, SCLK, SAFE	I_{OL} = 0.5 mA			0.4	V
	Output voltage low LED1, LED2, LED3, LED4, LED5	I_{OL} = 10 mA			0.4	V
V_{OH}	Output voltage high SMBC, SMBD, SDATA, SCLK, SAFE	I_{OH} = –1 mA	V_{CC} – 0.5			V
V_{IL}	Input voltage low $\overline{SMBC}$, $\overline{SMBD}$, SDATA, SCLK, XALERT, $\overline{PRES}$, $\overline{PFIN}$, DISP		–0.3		0.8	V

(1)   This value does not include the bq29330

Product Folder Link(s) :*bq20z60-R1*

ELECTRICAL CHARACTERISTICS (continued)

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IH}	Input voltage high SMBC, SMBD, SDATA, SCLK, XALERT, PRES, PFIN		2		6	V
	Input voltage high DISP		2		V_{CC} + 0.3	V
C_{IN}	Input capacitance			5		pF
$V_{(AI1)}$	Input voltage range VCELL+, VCELL–,TS1, TS2		–0.2		0.8 x V_{CC}	V
$V_{(AI2)}$	Input voltage range SRN, SRP		–0.20		0.20	
$Z_{(AI2)}$	Input impedance VCELL+, VCELL–, TS1, TS2	0 V–1 V	8			MΩ
$Z_{(AI1)}$	Input impedance SRN, SRP	0 V–1 V	2.5			MΩ

POWER-ON RESET

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{IT–}$	Negative-going voltage input		1.7	1.8	1.9	V
V_{HYS}	Power-on reset hysteresis		50	125	200	mV

POWER ON RESET BEHAVIOR
VS
FREE-AIR TEMPERATURE
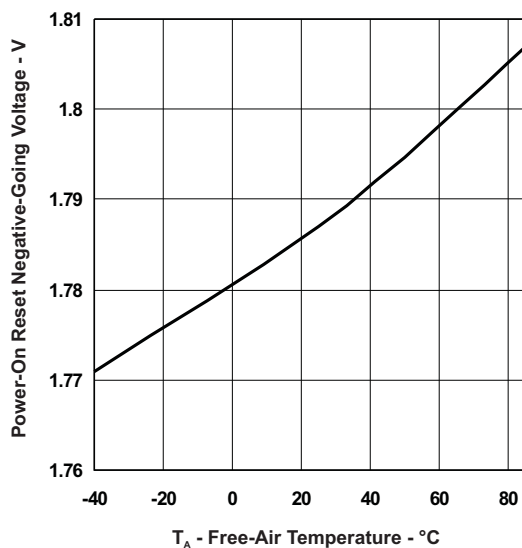
INTEGRATING ADC (Coulomb Counter) CHARACTERISTICS

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(SR)}$	Input voltage range, $V_{(SRN)}$ and $V_{(SRP)}$	$V_{(SR)} = V_{(SRN)} – V_{(SRP)}$	–0.2		0.2	V
$V_{(SROS)}$	Input offset			10		µV
INL	Integral nonlinearity error			0.007	0.034	%

OSCILLATOR

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
HIGH FREQUENCY OSCILLATOR					

OSCILLATOR (continued)

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$f_{(OSC)}$	Operating frequency				4.194	MHz
$f_{(EIO)}$	Frequency error [1] [2]		–3	0.25	3	%
		T_A = 20°C to 70°C	–2	0.25	2	
$t_{(SXO)}$	Start-up time [3]			2.5	5	ms
LOW FREQUENCY OSCILLATOR						
$f_{(LOSC)}$	Operating frequency			32.768		kHz
$f_{(LEIO)}$	Frequency error [2] [4]		–2.5	0.25	2.5	%
		T_A = 20°C to 70°C	–1.5	0.25	1.5	
$t_{(LSXO)}$	Start-up time [5]				500	µs

(1) The frequency error is measured from 4.194 MHz.
(2) The frequency drift is included and measured from the trimmed frequency at V_{CC} = 2.5 V, T_A = 25°C.
(3) The start-up time is defined as the time it takes for the oscillator output frequency to be within 1 % of the specified frequency.
(4) The frequency error is measured from 32.768 kHz.
(5) The start-up time is defined as the time it takes for the oscillator output frequency to be ± 3%.

DATA FLASH MEMORY CHARACTERISTICS

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{DR}	Data retention	See [1]	10			Years
	Flash programming write-cycles	See [1]	20,000			Cycles
$t_{(WORDPROG)}$	Word programming time	See [1]			2	ms
$I_{(DDdPROG)}$	Flash-write supply current	See [1]		5	10	mA

(1) Specified by design. Not production tested.

REGISTER BACKUP

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(RB)}$	RB data-retention input current	$V_{(RB)}$ > $V_{(RBMIN)}$, V_{CC} < $V_{IT–}$			1500	nA
		$V_{(RB)}$ > $V_{(RBMIN)}$, V_{CC} < $V_{IT–}$, T_A = 0°C to 50°C		40	160	
$V_{(RB)}$	RB data-retention voltage [1]		1.7			V

(1) Specified by design. Not production tested.

SMBus TIMING SPECIFICATIONS

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{SMB}	SMBus operating frequency	Slave mode, SMBC 50% duty cycle	10		100	kHz
f_{MAS}	SMBus master clock frequency	Master mode, no clock low slave extend		51.2		
t_{BUF}	Bus free time between start and stop		4.7			µs
$t_{HD:STA}$	Hold time after (repeated) start		4			
$t_{SU:STA}$	Repeated start setup time		4.7			
$t_{SU:STO}$	Stop setup time		4			
$t_{HD:DAT}$	Data hold time	Receive mode	0			ns
		Transmit mode	300			
$t_{SU:DAT}$	Data setup time		250			
$t_{TIMEOUT}$	Error signal/detect	See [1]	25		35	ms

(1) The bq20z60-R1 times out when any clock low exceeds $t_{TIMEOUT}$.

Product Folder Link(s) :bq20z60-R1

SMBus TIMING SPECIFICATIONS (continued)

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{LOW}	Clock low period		4.7			μs
t_{HIGH}	Clock high period	See [2]	4		50	
$t_{LOW:SEXT}$	Cumulative clock low slave extend time	See [3]			25	ms
$t_{LOW:MEXT}$	Cumulative clock low master extend time	See [4]			10	
t_F	Clock/data fall time	(V_{ILMAX} – 0.15 V) to (V_{IHMIN} + 0.15 V)			300	ns
t_R	Clock/data rise time	0.9 V_{CC} to (V_{ILMAX} – 0.15 V)			1000	

(2) $t_{HIGH:MAX}$ is minimum bus idle time. SMBC = 1 for t > 50 μs causes reset of any transaction involving the bq20z60-R1 that is in progress.
(3) $t_{LOW:SEXT}$ is the cumulative time a slave device is allowed to extend the clock cycles in one message from initial start to the stop.
(4) $t_{LOW:MEXT}$ is the cumulative time a master device is allowed to extend the clock cycles in one message from initial start to the stop.
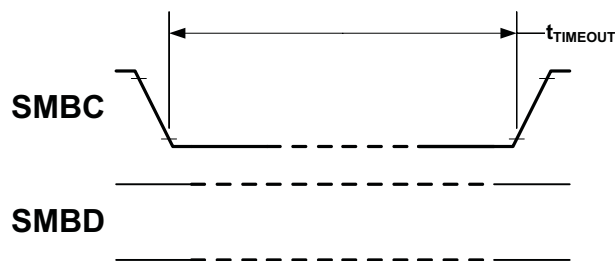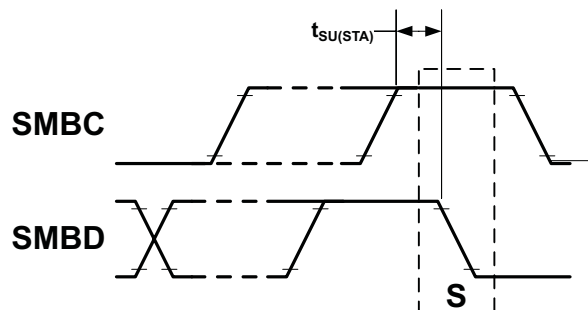
SMBus TIMING DIAGRAM
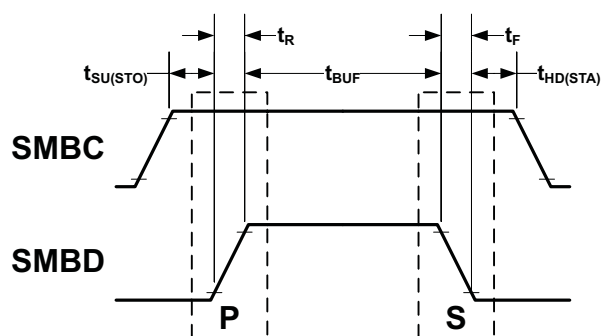
Start and Stop condition
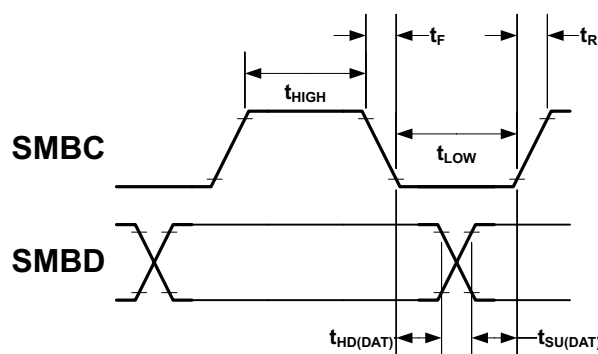
Wait and Hold condition

Timeout condition

Repeated Start condition

A.   SCLKACK is the acknowledge related clock pulse generated by the master.

FEATURE SET

Primary (1st Level) Safety Features

The bq20z60-R1 supports a wide range of battery and system protection features that can easily be configured. The primary safety features include:

- Cell over/undervoltage protection
- Charge and discharge overcurrent
- Short circuit protection
- Charge and discharge overtemperature with independent alarms and thresholds for each thermistor
- AFE Watchdog

Secondary (2nd Level) Safety Features

The secondary safety features of the bq20z60-R1 can be used to indicate more serious faults via the SAFE pin. This pin can be used to blow an in-line fuse to permanently disable the battery pack from charging or discharging. The secondary safety protection features include:

- Safety overvoltage
- Safety undervoltage
- 2nd level protection IC input
- Safety over current in charge and discharge
- Safety overtemperature in charge and discharge with independent alarms and thresholds for each thermistor
- Charge FET and zero-volt Charge FET fault
- Discharge FET fault
- Cell imbalance detection (active and at rest)
- Open thermistor detection
- AFE communication fault

Charge Control Features

The bq20z60-R1 charge control features include:

- Supports JEITA temperature ranges. Reports charging voltage and charging current according to the active temperature range
- Handles more complex charging profiles. Allows for splitting the standard temperature range into two sub-ranges and allows for varying the charging current according to the cell voltage.
- Reports the appropriate charging current needed for constant current charging and the appropriate charging voltage needed for constant voltage charging to a smart charger using SMBus broadcasts
- Determines the chemical state of charge of each battery cell using Impedance Track, and reduces the charge difference of the battery cells in fully charged state of the battery pack, gradually using the cell balancing algorithm during charging. This prevents fully charged cells from overcharging and causing excessive degradation, and also increases the usable pack energy by preventing premature charge termination.
- Supports pre-charging/zero-volt charging
- Supports charge inhibit and charge suspend if battery pack temperature is out of temperature range
- Reports charging fault and also indicate charge status via charge and discharge alarms

Gas Gauging

The bq20z60-R1 uses the Impedance Track technology to measure and calculate the available charge in battery cells. The achievable accuracy is better than 1% error over the lifetime of the battery and there is no full charge discharge learning cycle required.

See *Theory and Implementation of Impedance Track Battery Fuel-Gauging Algorithm* application note (SLUA364) for further details.

Lifetime Data Logging Features

The bq20z60-R1 offers lifetime data logging, where important measurements are stored for warranty and analysis purposes. The data monitored includes:

- Lifetime maximum temperature
- Lifetime maximum temperature count
- Lifetime maximum temperature duration
- Lifetime minimum temperature
- Lifetime maximum battery cell voltage
- Lifetime maximum battery cell voltage count
- Lifetime maximum battery cell voltage duration
- Lifetime minimum battery cell voltage
- Lifetime maximum battery pack voltage
- Lifetime minimum battery pack voltage
- Lifetime maximum charge current
- Lifetime maximum discharge current
- Lifetime maximum charge power
- Lifetime maximum discharge power
- Lifetime maximum average discharge current
- Lifetime maximum average discharge power
- Lifetime average temperature

Authentication

The bq20z60-R1 supports authentication by the host using SHA-1.

Power Modes

The bq20z60-R1 supports three separate power modes to reduce power consumption:

- In Normal Mode, the bq20z60-R1 performs measurements, calculations, protection decisions, and data updates in 1-s intervals. Between these intervals, the bq20z60-R1 is in a reduced power stage.
- In Sleep Mode, the bq20z60-R1 performs measurements, calculations, protection decisions, and data updates in adjustable time intervals. Between these intervals, the bq20z60-R1 is in a reduced power stage. The bq20z60-R1 has a wake function that enables exit from Sleep mode when current flow or failure is detected.
- In Shutdown Mode, the bq20z60-R1 is completely disabled.

CONFIGURATION

Oscillator Function

The bq20z60-R1 fully integrates the system oscillators; therefore, no external components are required for this feature.

System Present Operation

The bq20z60-R1 periodically verifies the $\overline{PRES}$ pin and detects that the battery is present in the system via a low state on a $\overline{PRES}$ input. When this occurs, the bq20z60-R1 enters normal operating mode. When the pack is removed from the system and the $\overline{PRES}$ input is high, the bq20z60-R1 enters the battery-removed state, disabling the charge, discharge, and ZVCHG FETs. The $\overline{PRES}$ input is ignored and can be left floating when non-removal mode is set in the data flash.

BATTERY PARAMETER MEASUREMENTS

The bq20z60-R1 uses an integrating delta-sigma analog-to-digital converter (ADC) for current measurement, and a second delta-sigma ADC for individual cell and battery voltage and temperature measurement.

Charge and Discharge Counting

The integrating delta-sigma ADC measures the charge/discharge flow of the battery by measuring the voltage drop across a small-value sense resistor between the SRP and SRN pins. The integrating ADC measures bipolar signals from –0.25 V to 0.25 V. The bq20z60-R1 detects charge activity when $V_{SR} = V_{(SRP)} - V_{(SRN)}$ is positive and discharge activity when $V_{SR} = V_{(SRP)} - V_{(SRN)}$ is negative. The bq20z60-R1 continuously integrates the signal over time, using an internal counter. The fundamental rate of the counter is 0.65 nVh.

Voltage

The bq20z60-R1 updates the individual series cell voltages through the bq29330 at 1-s intervals. The bq20z60-R1 configures the bq29330 to connect the selected cell, cell offset, or bq29330 VREF to the CELL pin of the bq29330, which is required to be connected to VIN of the bq20z60-R1. The internal ADC of the bq20z60-R1 measures the voltage, scales it, and calibrates itself appropriately. This data is also used to calculate the impedance of the cell for the Impedance Track gas-gauging.

Current

The bq20z60-R1 uses the SRP and SRN inputs to measure and calculate the battery charge and discharge current using a 5-mΩ to 20-mΩ typ. sense resistor.

Wake Function

The bq20z60-R1 can exit sleep mode, if enabled, by the presence of a programmable level of current signal across SRP and SRN.

Auto Calibration

The bq20z60-R1 provides an auto-calibration feature to cancel the voltage offset error across SRP and SRN for maximum charge measurement accuracy. The bq20z60-R1 performs auto-calibration when the SMBus lines stay low continuously for a minimum of a programmable amount of time.

Temperature

The bq20z60-R1 has an internal temperature sensor and inputs for two external temperature sensors, TS1 and TS2, used in conjunction with two identical NTC thermistors (default are Semitec 103AT) to sense the battery environmental temperature. The bq20z60-R1 can be configured to use the internal temperature sensor, or up to two external temperature sensors.

COMMUNICATIONS

The bq20z60-R1 uses SMBus v1.1 with Master Mode and package error checking (PEC) options per the SBS specification.

SMBus On and Off State

The bq20z60-R1 detects an SMBus off state when SMBC and SMBD are logic-low for ≥ 2 seconds. Clearing this state requires either SMBC or SMBD to transition high. Within 1 ms, the communication bus is available.
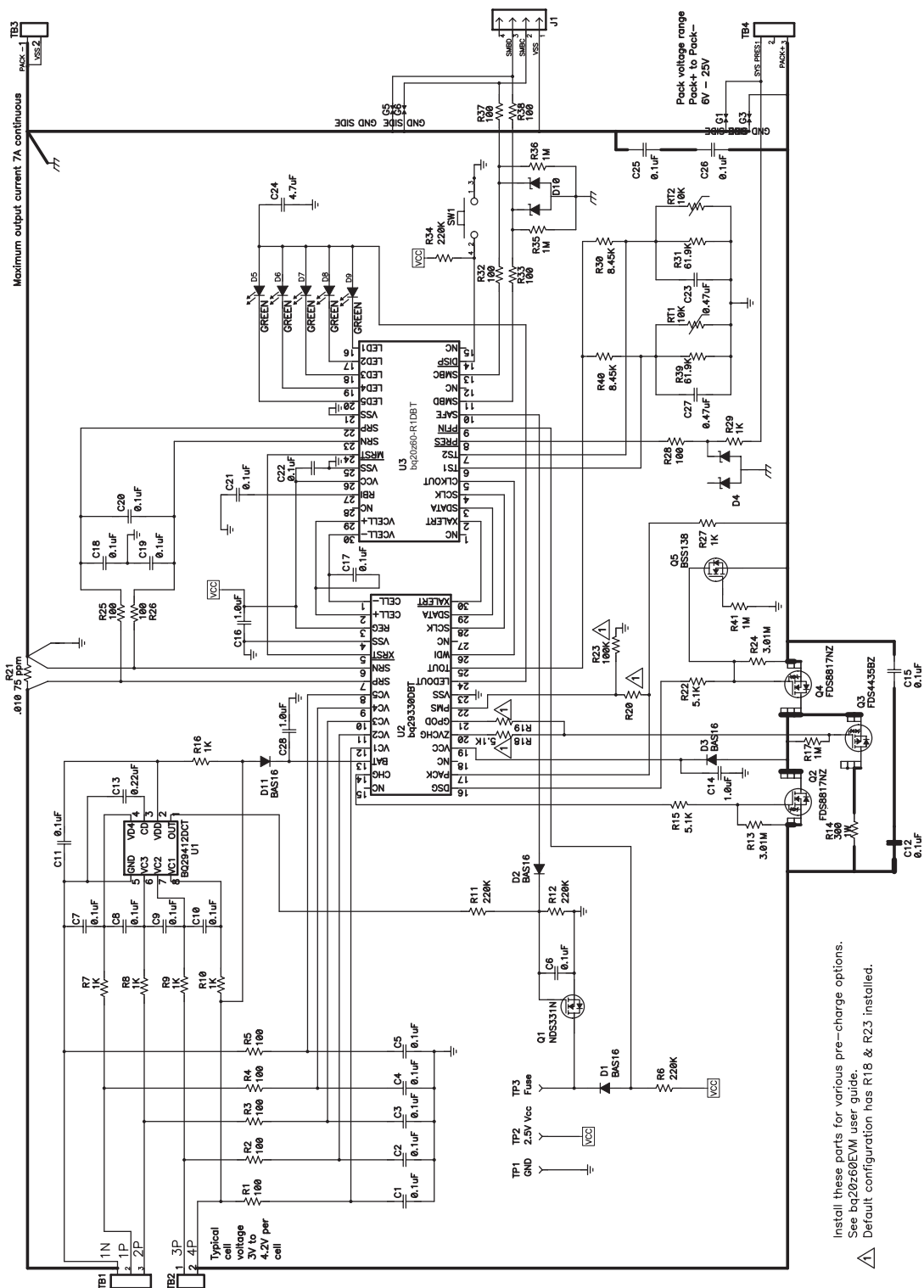
Product Folder Link(s) :*bq20z60-R1*

SBS Commands

Table 3. SBS COMMANDS

SBS CMD	MODE	NAME	FORMAT	SIZE IN BYTES	MIN VALUE	MAX VALUE	DEFAULT VALUE	UNIT
0x00	R/W	ManufacturerAccess	Hex	2	0x0000	0xffff	—	—
0x01	R/W	RemainingCapacityAlarm	Integer	2	0	700 or 1000	300 or 432	mAh or 10 mWh
0x02	R/W	RemainingTimeAlarm	Unsigned Integer	2	0	30	10	min
0x03	R/W	BatteryMode	Hex	2	0x0000	0xffff	—	—
0x04	R/W	AtRate	Integer	2	–32,768	32,767	0	mA or 10 mW
0x05	R	AtRateTimeToFull	Unsigned Integer	2	0	65,535	—	min
0x06	R	AtRateTimeToEmpty	Unsigned Integer	2	0	65,535	—	min
0x07	R	AtRateOK	Unsigned Integer	2	0	65,535	—	—
0x08	R	Temperature	Unsigned Integer	2	0	65,535	—	0.1°K
0x09	R	Voltage	Unsigned Integer	2	0	20,000	—	mV
0x0a	R	Current	Integer	2	–32,768	32,767	—	mA
0x0b	R	AverageCurrent	Integer	2	–32,768	32,767	—	mA
0x0c	R	MaxError	Unsigned Integer	1	0	100	—	%
0x0d	R	RelativeStateOfCharge	Unsigned Integer	1	0	100	—	%
0x0e	R	AbsoluteStateOfCharge	Unsigned Integer	1	0	100+	—	%
0x0f	R/W	RemainingCapacity	Unsigned Integer	2	0	65,535	—	mAh or 10 mWh
0x10	R	FullChargeCapacity	Unsigned Integer	2	0	65,535	—	mAh or 10 mWh
0x11	R	RunTimeToEmpty	Unsigned Integer	2	0	65,534	—	min
0x12	R	AverageTimeToEmpty	Unsigned Integer	2	0	65,534	—	min
0x13	R	AverageTimeToFull	Unsigned Integer	2	0	65,534	—	min
0x14	R	ChargingCurrent	Unsigned Integer	2	0	65,534	—	mA
0x15	R	ChargingVoltage	Unsigned Integer	2	0	65,534	—	mV
0x16	R	BatteryStatus	Hex	2	0x0000	0xdbff	—	—
0x17	R/W	CycleCount	Unsigned Integer	2	0	65,535	0	—
0x18	R/W	DesignCapacity	Integer	2	0	32,767	4400 or 6336	mAh or 10 mWh
0x19	R/W	DesignVoltage	Integer	2	7000	18,000	14,400	mV
0x1a	R/W	SpecificationInfo	Hex	2	0x0000	0xffff	0x0031	—
0x1b	R/W	ManufactureDate	Unsigned Integer	2	—	65,535	0	—
0x1c	R/W	SerialNumber	Hex	2	0x0000	0xffff	0	—
0x20	R/W	ManufacturerName	String	11+1	—	—	Texas Instruments	—
0x21	R/W	DeviceName	String	7+1	—	—	bq20z60-R1	—
0x22	R/W	DeviceChemistry	String	4+1	—	—	LION	—
0x23	R/W	ManufacturerData	String	14+1	—	—	—	—
0x2f	R/W	Authenticate	String	20+1	—	—	—	—
0x3c	R	CellVoltage4	Unsigned Integer	2	0	65,535	—	mV
0x3d	R	CellVoltage3	Unsigned Integer	2	0	65,535	—	mV
0x3e	R	CellVoltage2	Unsigned Integer	2	0	65,535	—	mV
0x3f	R	CellVoltage1	Unsigned Integer	2	0	65,535	—	mV

Table 4. EXTENDED SBS COMMANDS

SBS CMD	MODE	NAME	FORMAT	SIZE IN BYTES	MIN VALUE	MAX VALUE	DEFAULT VALUE	UNIT
0x45	R	AFEData	String	11+1	—	—	—	—
0x46	R/W	FETControl	Hex	2	0x00	0xff	—	—
0x4f	R	StateOfHealth	Hex	2	0x0000	0xffff	—	—
0x50	R	SafetyAlert	Hex	2	0x0000	0xffff	—	—
0x51	R	SafetyStatus	Hex	2	0x0000	0xffff	—	—
0x52	R	PFAlert	Hex	2	0x0000	0xffff	—	—
0x53	R	PFStatus	Hex	2	0x0000	0xffff	—	—
0x54	R	OperationStatus	Hex	2	0x0000	0xffff	—	—
0x55	R	ChargingStatus	Hex	2	0x0000	0xffff	—	—
0x57	R	ResetData	Hex	2	0x0000	0xffff	—	—
0x58	R	WDResetData	Unsigned Integer	2	0	65,535	—	—
0x5a	R	PackVoltage	Unsigned Integer	2	0	65,535	—	mV
0x5d	R	AverageVoltage	Unsigned Integer	2	0	65,535	—	mV
0x5e	R	TS1Temperature	Integer	2	–400	1200	—	0.1°C
0x5f	R	TS2Temperature	Integer	2	–400	1200	—	0.1°C
0x60	R/W	UnSealKey	Hex	4	0x00000000	0xffffffff	—	—
0x61	R/W	FullAccessKey	Hex	4	0x00000000	0xffffffff	—	—
0x62	R/W	PFKey	Hex	4	0x00000000	0xffffffff	—	—
0x63	R/W	AuthenKey3	Hex	4	0x00000000	0xffffffff	—	—
0x64	R/W	AuthenKey2	Hex	4	0x00000000	0xffffffff	—	—
0x65	R/W	AuthenKey1	Hex	4	0x00000000	0xffffffff	—	—
0x66	R/W	AuthenKey0	Hex	4	0x00000000	0xffffffff	—	—
0x68	R	SafetyAlert2	Hex	2	0x0000	0x000f	—	—
0x69	R	SafetyStatus2	Hex	2	0x0000	0x000f	—	—
0x6a	R	PFAlert2	Hex	2	0x0000	0x000f	—	—
0x6b	R	PFStatus2	Hex	2	0x0000	0x000f	—	—
0x6c	R/W	ManufBlock1	String	20	—	—	—	—
0x6d	R/W	ManufBlock2	String	20	—	—	—	—
0x6e	R/W	ManufBlock3	String	20	—	—	—	—
0x6f	R/W	ManufBlock4	String	20	—	—	—	—
0x70	R/W	ManufacturerInfo	String	31+1	—	—	—	—
0x71	R/W	SenseResistor	Unsigned Integer	2	0	65,535	—	µΩ
0x72	R	TempRange	Hex	2	0x0000	0xffff	—	—
0x73	R	LifetimeData1	String	32+1	—	—	—	—
0x74	R	LifetimeData2	String	8+1	—	—	—	—
0x77	R/W	DataFlashSubClassID	Hex	2	0x0000	0xffff	—	—
0x78	R/W	DataFlashSubClassPage1	Hex	32	—	—	—	—
0x79	R/W	DataFlashSubClassPage2	Hex	32	—	—	—	—
0x7a	R/W	DataFlashSubClassPage3	Hex	32	—	—	—	—
0x7b	R/W	DataFlashSubClassPage4	Hex	32	—	—	—	—
0x7c	R/W	DataFlashSubClassPage5	Hex	32	—	—	—	—
0x7d	R/W	DataFlashSubClassPage6	Hex	32	—	—	—	—
0x7e	R/W	DataFlashSubClassPage7	Hex	32	—	—	—	—
0x7f	R/W	DataFlashSubClassPage8	Hex	32	—	—	—	—

Product Folder Link(s) :*bq20z60-R1*

APPLICATION SCHEMATIC

REVISION HISTORY

Product Folder Link(s) :*bq20z60-R1*

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
BQ20Z60DBT-R1	ACTIVE	TSSOP	DBT	30	60	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	20Z60	Samples
BQ20Z60DBTR-R1	ACTIVE	TSSOP	DBT	30	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	20Z60	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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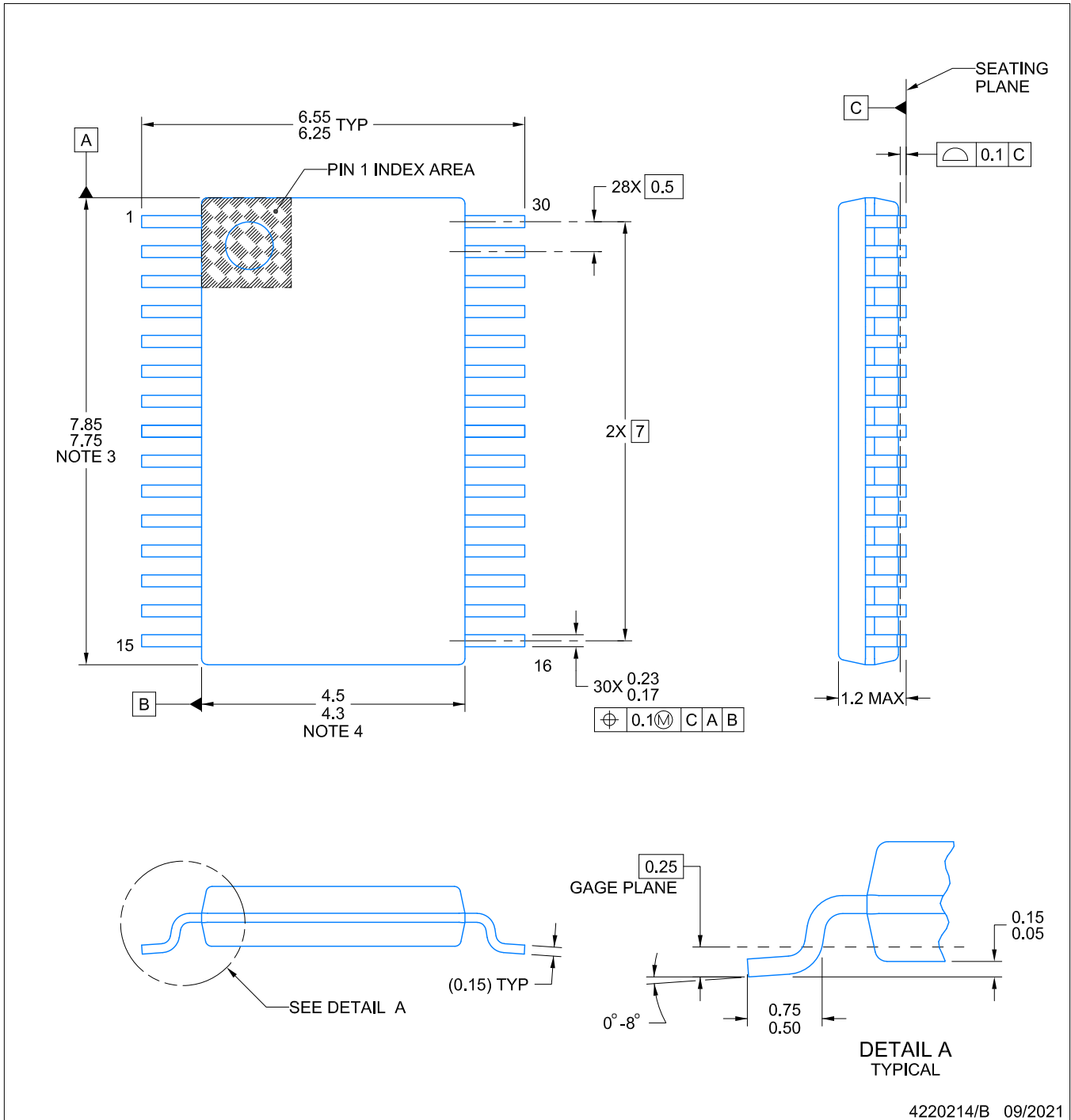**TUBE**

*All dimensions are nominal

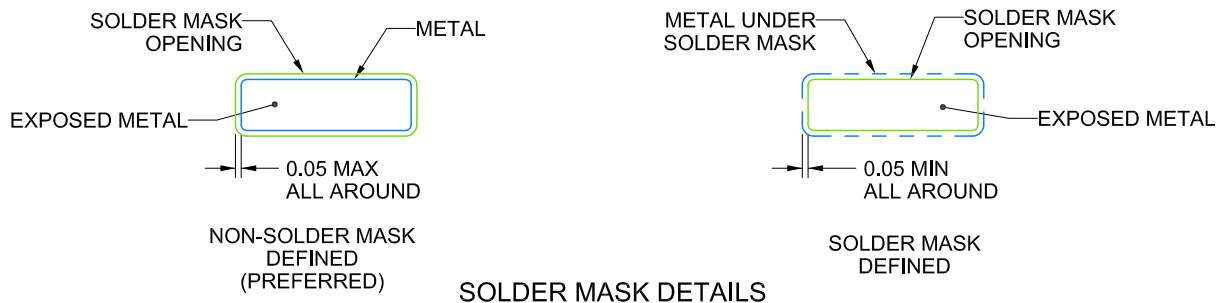| Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
BQ20Z60DBT-R1	DBT	TSSOP	30	60	530	10.2	3600	3.5

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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

30X (1.5)

SYMM

1

(R0.05) TYP

30

30X (0.3)

30X (0.5)

SYMM

15

16

(5.8)
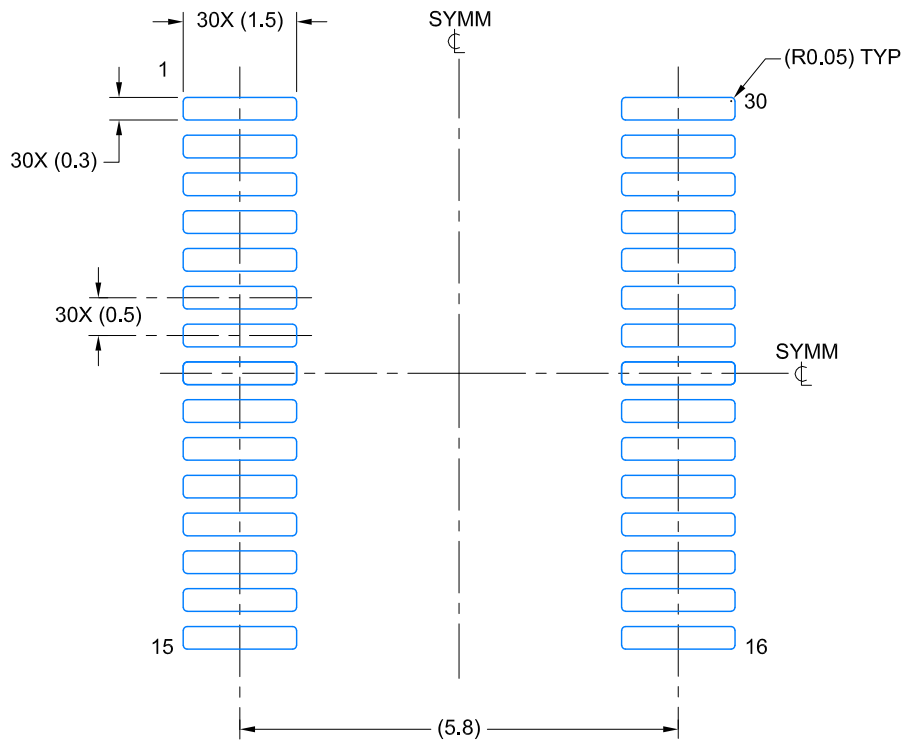
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.05 MIN
ALL AROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
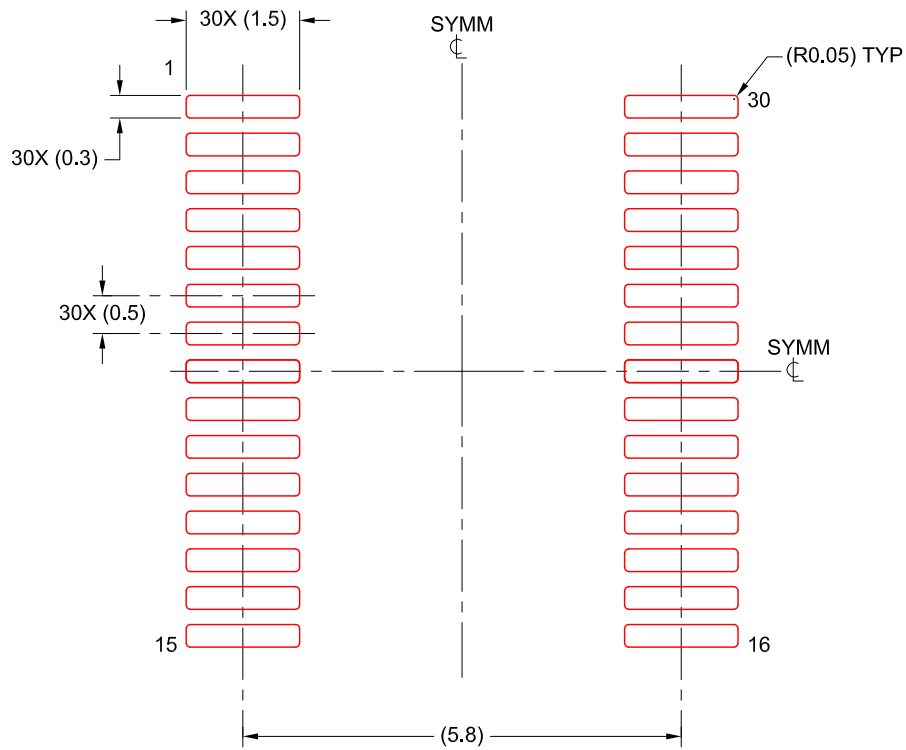
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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